TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

# 2SA1360

## Audio Frequency Amplifier Applications

Unit: mm

- Complementary to 2SC3423
- Small collector output capacitance: Cob = 2.5 pF (typ.)
- High transition frequency: fT = 200 MHz (typ.)

## Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	-150	V	
Collector-emitter voltage		V <sub>CEO</sub>	-150	V	
Emitter-base voltage		V <sub>EBO</sub>	-5	V	
Collector current		IC	-50	mA	
Base current		Ι <sub>Β</sub>	-5	mA	
Collector power dissipation	Ta = 25°C	Pc	1.2	W	
	Tc = 25°C		5		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

Weight: 0.82 g (typ.)

operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

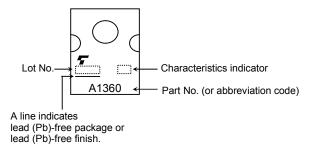


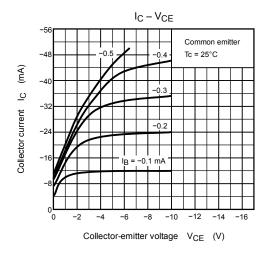
## **Electrical Characteristics (Tc = 25°C)**

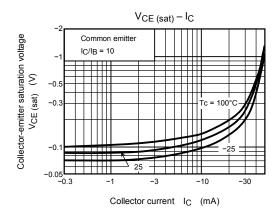
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = −150 V, I <sub>E</sub> = 0	_	_	-0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_C = 0$	_	1	-0.1	μA
Collector-emitter breakdown voltage	V <sub>(BR)</sub> CEO	$I_C = -1 \text{ mA}, I_B = 0$	-150	_	_	V
DC current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -10 mA	80	_	240	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = -10 mA, I <sub>B</sub> = -1 mA	_	_	-1.0	V
Base-emitter voltage	V <sub>BE</sub>	$V_{CE} = -5 \text{ V, } I_{C} = -10 \text{ mA}$	_	_	-0.8	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -5 \text{ V, } I_{C} = -10 \text{ mA}$	_	200	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = −10 V, I <sub>E</sub> = 0, f = 1 MHz	_	2.5	_	pF

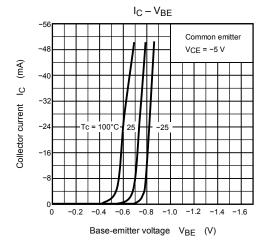
Note: hFE classification O: 80 to 160, Y: 120 to 240

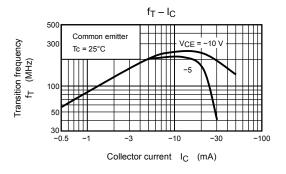
## Marking

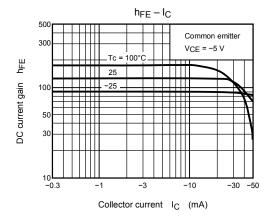


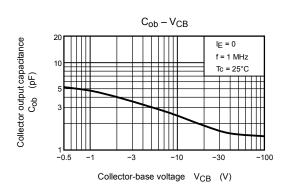


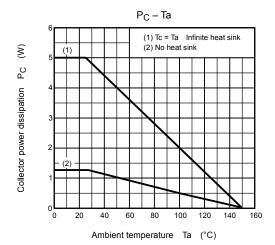












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